	Application No.	Applicant(s)	
		HENSON TIMOTUV	,
Notice of Allowability	10/761,484 Examiner	HENSON, TIMOTHY Art Unit	
	Fazli Erdem	2826	NJR
The MAILING DATE of this communication appe All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI of the Office or upon petition by the applicant. See 37 CFR 1.313	ears on the cover sheet with the of (OR REMAINS) CLOSED in this apport or other appropriate communication (GHTS. This application is subject and MPEP 1308.	correspondence addre oplication. If not include on will be mailed in due of	ess d course. THIS
1. This communication is responsive to Amendment filed on 0	<u>06/15/2005</u> .		
2. The allowed claim(s) is/are 1-15 and 17.		1	
3. X The drawings filed on 20 January 2004 and 15 June 2005	are accepted by the Examiner.		<u></u>
4. ☐ Acknowledgment is made of a claim for foreign priority una) ☐ All b) ☐ Some* c) ☐ None of the: 1. ☐ Certified copies of the priority documents have 2. ☐ Certified copies of the priority documents have 3. ☐ Copies of the certified copies of the priority documents have International Bureau (PCT Rule 17.2(a)). * Certified copies not received: Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE. 5. ☐ A SUBSTITUTE OATH OR DECLARATION must be subminsformal PATENT APPLICATION (PTO-152) which give	e been received. e been received in Application No cuments have been received in this of this communication to file a reply IENT of this application. itted. Note the attached EXAMINER es reason(s) why the oath or declar	c national stage application of Notice to the stage application of the stage application of the stage application of the stage application of the stage application and stage application of the sta	TENT EXAMINER CENTER 2800 ion from the uirements
6. CORRECTED DRAWINGS (as "replacement sheets") mus			
(a) ☐ including changes required by the Notice of Draftspers1) ☐ hereto or 2) ☐ to Paper No./Mail Date	· · · · · · · · · · · · · · · · · ·	-948) attached	
(b) ☐ including changes required by the attached Examiner's Paper No./Mail Date		Office action of	
Identifying indicia such as the application number (see 37 CFR 1, each sheet, Replacement sheet(s) should be labeled as such in t			back) of
7. DEPOSIT OF and/or INFORMATION about the deposit attached Examiner's comment regarding REQUIREMENT			ote the
Attachment(s) 1. ☐ Notice of References Cited (PTO-892) 2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948) 3. ☐ Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date	5. Notice of Informal 6. Interview Summary Paper No./Mail Da 7. Examiner's Amend 8. Examiner's Statem 9. Other	y (PTO-413), ate Iment/Comment	·

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DETAILED ACTION

Allowable Subject Matter

1. Claims 1-15 and 17 allowed.

2. The following is an examiner's statement of reasons for allowance: Prior art failed to establish a semiconductor device comprising a semiconductor region of first conductivity formed over a semiconductor substrate of first conductivity, a semiconductor trench receiving region formed over semiconductor region of first conductivity, plurality of trenches in trench receiving region each trench including a bottom surface and opposing sidewall, a channel region of second conductivity adjacent to trenches, a conductive column of first conductivity directly under the bottom surface of a respective trench and reaching semiconductor region of first conductivity, a region of second conductivity adjacent and lateral to each conductive column where the region in charge balance with conductive column and adjacent to channel region, conductive regions of first conductivity type adjacent each trench and in channel region, a gate insulation layer on sidewalls of trenches, a gate electrode in each trench and an electrical contact layer over trench receiving region and in contact with conductive regions of first conductivity.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Conclusion

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Any inquiry concerning this communication or earlier communications from the examiner should be directed to Fazli Erdem whose telephone number is (571) 272-1914. The examiner can normally be reached on M - F 8:00 - 5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan Flynn can be reached on (571) 272-1915. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

FE August 8, 2005